

# **QX2E8 Series**

#### **Description**

Gas discharge Tubes (GDT) are classical components for protecting the installations of the telecommunications. It is essential that IT and telecommunications systems -with their high-grade but sensitive electronic circuits - be protected by arresters. They are thus fitted at the input of the power supply system together with varistors and at the connection points to telecommunication lines. They have become equally indispensable for protecting base stations in mobile telephone systems as well as extensive cable television (CATV) networks with their repeaters and distribution systems.

These protective components are also indispensable in other sectors, In AC power transmission systems, they are often used with current-limiting varistors, In customer premises equipment such as DSL modems, WLAN routers, TV sets and cable modems In air-conditioning equipment, the integral black-box concept offers graduated protection by combining arresters with varistors, PTC, diodes and inductor.

#### **Features**

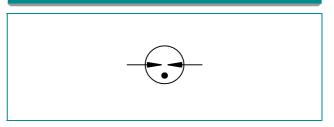
- u Non-Radioactive
- u RoHS compliant
- u High insulation resistance
- u Excellent response to fast rising transients
- Ultra low capacitance
- u 10~20KA surge capability tested with 8/20μs pulse as defined by IEC 61000-4-5

### **Applications**

- u Communication lines and equipment
- u CATV equipment
- u Test equipment
- u Data lines
- **u** Power supplies
- u Instrumentation circuits
- u Medical electronics
- u ADSL equipment
- u Telecom SLIC protection



### **Schematic Symbol**



# **Agency Approvals**

AGENCY	AGENCY FILE NUMBER
<b>71</b> °	E466847

#### **Product Characteristics**

Materials	Leaded Device: Nic Tinplated wires Surface Mount: Dull Tin-	ckel-plated with					
Product Marking	XXX -Nominal voltage  M - 10KA  H - 20KA						
Glow to Arc Transition Current	< 0.5 Amps						
Glow Voltage	~60 Volts						
Storage and Operational Temperature	-40 to +90°C						
	QX2E8-XXXML	~1.5g					
Woight	QX2E8-XXXHL	~1.6g					
Weight	QX2E8-XXXM/H	~1.35g					
	QX2E8-XXXM/HSMD	~1.5g					

QIAOXIN Semiconductor Co.,Ltd

www.qiaoxin-semi.com

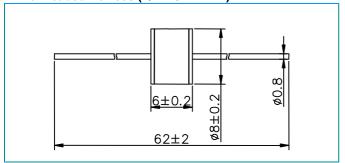


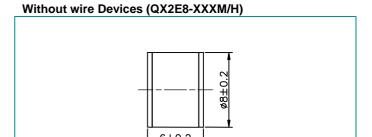
# **QX2E8 Series**

### Dimensions

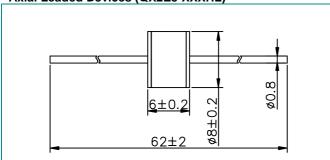
#### **Unit: mm**

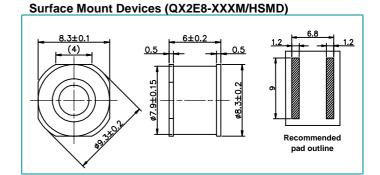
# Axial Leaded Devices (QX2E8-XXXML)





# **Axial Leaded Devices (QX2E8-XXXHL)**





# **Electrical Characteristics**

								Service Life			
Part Number	Marking	DC Spark-over Voltage	Maximum Spark-ove		Minimum Insulation Resistance	Maximum Capacitance	Arc Voltage	Nominal Impulse Discharge Current	Max Impulse Discharge Current	Nominal Impulse Discharge Current	Impulse Life
		@100V/S	@100V/μs	@1KV/μs		@1MHz	@1A	@8/20μs ±5 times	@8/20μs 1 time	@50Hz 1 Sec 10 times	@10/1000µs 300 times
QX2E8-75M QX2E8-75ML QX2E8-75MSMD	75M	75V±20%	500V	600V	1 GΩ (at 25V)	1.5pF	~15V	10KA	20KA	10A	100A
QX2E8-90M QX2E8-90ML QX2E8-90MSMD	90M	90V±20%	500V	600V	1 GΩ (at 50V)	1.5pF	~15V	10KA	20KA	10A	100A
QX2E8-150M QX2E8-150ML QX2E8-150MSMD	150M	150V±20%	500V	600V	1 GΩ (at 50V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-230M QX2E8-230ML QX2E8-230MSMD	230M	230V±20%	600V	700V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-250M QX2E8-250ML QX2E8-250MSMD	250M	250V±20%	700V	800V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-300M QX2E8-300ML QX2E8-300MSMD	300M	300V±20%	800V	900V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-350M QX2E8-350ML QX2E8-350MSMD	350M	350V±20%	800V	900V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A



# **QX2E8 Series**

# **Electrical Characteristics (Continue)**

								Service Life			
Part Number	Marking	DC Spark-over Voltage	Maximum Impulse Spark-over Voltage		Minimum Insulation Resistance	Maximum Capacitance	Arc Voltage	Nominal Impulse Discharge Current	Max Impulse Discharge Current	Nominal Impulse Discharge Current	Impulse Life
		@100V/S	@100V/μs	@1KV/μs		@1MHz	@1A	@8/20μs ±5 times	@8/20μs 1 time	@50Hz 1 Sec 10 times	@10/1000μs 300 times
QX2E8-420M QX2E8-420ML QX2E8-420MSMD	420M	420V±20%	900V	1000V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-470M QX2E8-470ML QX2E8-470MSMD	470M	470V±20%	900V	1000V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-600M QX2E8-600ML QX2E8-600MSMD	600M	600V±20%	1100V	1200V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
QX2E8-800M QX2E8-800ML QX2E8-800MSMD	800M	800V±20%	1200V	1400V	1 GΩ (at 100V)	1.5pF	~20V	10KA	20KA	10A	100A
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QX2E8-75H QX2E8-75HL QX2E8-75HSMD	75H	75V±20%	500V	600V	1 GΩ (at 25V)	1.5pF	~15V	20KA	25KA	20A	200A
QX2E8-90H QX2E8-90HL QX2E8-90HSMD	90H	90V±20%	500V	600V	1 GΩ (at 50V)	1.5pF	~15V	20KA	25KA	20A	200A
QX2E8-150H QX2E8-150HL QX2E8-150HSMD	150H	150V±20%	500V	600V	1 GΩ (at 50V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-230H QX2E8-230HL QX2E8-230HSMD	230H	230V±20%	600V	700V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-250H QX2E8-250HL QX2E8-250HSMD	250H	250V±20%	700V	800V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-300H QX2E8-300HL QX2E8-300HSMD	300H	300V±20%	800V	900V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-350H QX2E8-350HL QX2E8-350HSMD	350H	350V±20%	800V	900V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-420H QX2E8-420HL QX2E8-420HSMD	420H	420V±20%	900V	1000V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-470H QX2E8-470HL QX2E8-470HSMD	470H	470V±20%	900V	1000V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-600H QX2E8-600HL QX2E8-600HSMD	600H	600V±20%	1100V	1200V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
QX2E8-800H QX2E8-800HL QX2E8-800HSMD	800H	800V±20%	1200V	1400V	1 GΩ (at 100V)	1.5pF	~20V	20KA	25KA	20A	200A
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#### Notes:

- 1). Terms in accordance with ITU-T K.12 and GB/T 9043-2008
- 2). At delivery AQL 0.65 level  $\, \mathrm{II} \,$  , DIN ISO 2859

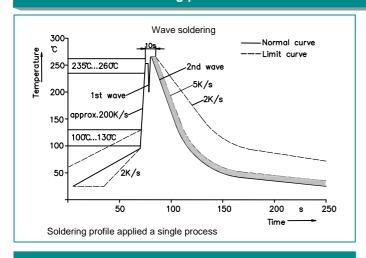


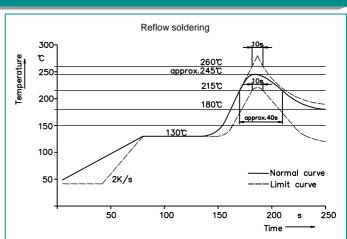
# **QX2E8 Series**

# **Electrical Rating**

Item	Test Condition / Description	Requirement
DC Spark-over Voltage Impulse Spark-over Voltage	The voltage is measured with a slowly rate of rise dv / dt=100V/s  The maximum impulse spark-over voltage is measured with a rise time of dv / dt=100V//µs or 1KV/µs	
Insulation Resistance	The resistance of gas tube shall be measured each terminal each other terminal, please see above spec.	
Capacitance	The capacitance of gas tube shall be measured each terminal to each other terminal.  Test frequency:1MHz	
Nominal Impulse Discharge Current  Nominal Alternating Discharge Current	The maximum current applying a waveform of 8/20µs that can be applied across the terminals of the gas tube. One hour after the test is completed, re-testing of the DC spark-over voltage does not exceed ±30% of the nominal DC spark-over voltage. Dwell time between pulses is 3 minutes.  Crest value  100 90 20 µsec  Time Impulse Width  Rated RMS value of AC current at 50Hz, 1 sec. 10 times. Intervals: 3min. The DC spark-over voltage does not exceed ±30% of the nominal DC spark-over voltage. IR > 10 <sup>8</sup> ohms.	To meet the specified value

### **Recommended soldering profile**





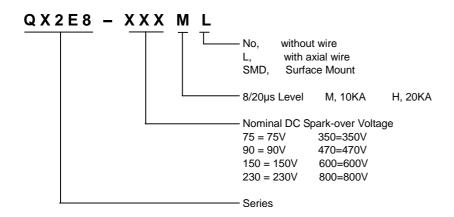
# **Soldering Parameters - Hand Soldering**

Solder Iron Temperature: 350°C +/-5°C Heating Time: 5 seconds max.



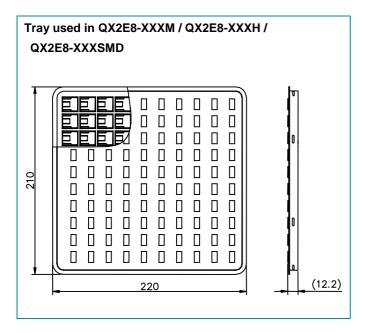
# **QX2E8 Series**

### **Part Numbering**



# Packaging Information Unit: mm

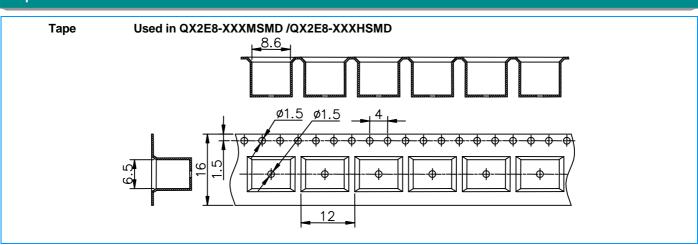
Part Number	Description	Quantity
QX2E8-XXXM / QX2E8XXXH	100PCS per Tray, 10 Trays / Inner Carton	1000
QX2E8-XXXML / QX2E8XXXHL	800PCS per Tape & Reel	800
OVOEO VVVMCMD / OVOEOVVVHCMD	100PCS per Tray, 10 Trays / Inner Carton	1000
QX2E8-XXXMSMD / QX2E8XXXHSMD	Tape & Reel -16mm tape/13"Reel	500

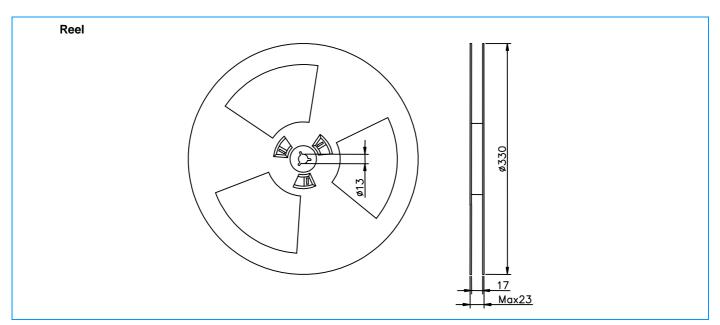




# **QX2E8 Series**

### Tape and Reel Dimensions Unit: mm





### Packaging Information (Continue) Unit: mm

- **u** Gas discharge tubes (GDT) must not be operated directly in power supply networks.
- u Gas discharge tubes (GDT) may become hot in case of longer periods of current stress (danger of burning).
- Gas discharge tubes (GDT) may be used only within their specified values. In the event of overload, the head contacts may fail or the component may be destroyed.
- u Damaged Gas discharge tubes (GDT) must not be re-used.